MOS FET Relays

Relay Incorporating a MOS FET Optically Coupled with an Infrared LED has a 4-pin SOP Package and 80-V Load Voltage

- Continuous load current of 350 mA.
- Dielectric strength of 1,500 Vrms between I/O.
- RoHS Compliant.

Application Examples

- Broadband systems
- Measurement devices
- Data loggers
- Amusement machines

List of Models



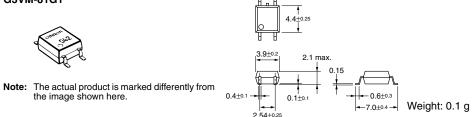
Note: The actual product is marked differently from the image shown here.

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
	Surface-mounting terminals	80 VAC	G3VM-81G1	100	
			G3VM-81G1(TR)		2,500

Dimensions

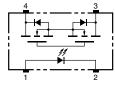
Note: All units are in millimeters unless otherwise indicated.

G3VM-81G1

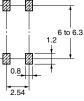


■ Terminal Arrangement/Internal Connections (Top View)

G3VM-81G1



■ Actual Mounting Pad Dimensions (Recommended Value, Top View) G3VM-81G1



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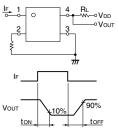
■ Absolute Maximum Ratings (Ta = 25°C)

Item		Symbol Rating		Unit	Measurement conditions]
Input	LED forward current	I _F	50	mA		Note
	Repetitive peak LED forward current	I _{FP}	1	A	100 μ s pulses, 100 pps	
	LED forward current reduction rate	$\Delta I_{\rm F}^{\prime \rm O}{\rm C}$	-0.5	mA/°C	$T_a \ge 25^{\circ}C$	
	LED reverse voltage	V _R	5	V		1
	Connection temperature	T _j	125	°C		1
Output	Load voltage (AC peak/DC)	V_{OFF}	80	V		1
	Continuous load current	I _o	350	mA		1
	ON current reduction rate	$\Delta \; {\rm I_{ON}}/{^{\rm o}{\rm C}}$	-3.5	mA/°C	$T_a \ge 25^{\circ}C$	1
	Connection temperature	T _j	125	°C		1
	ic strength between input and See note 1.)	V _{I-O}	1,500	Vrms	AC for 1 min	
Operating temperature		T _a	-40 to +85	°C	With no icing or condensation	
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation	1
Soldering temperature (10 s)			260	°C	10 s	1

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions	
Input	LED forward voltage	V _F	1.0	1.15	1.3	V	l _F = 10 mA	Note
	Reverse current	I _R			10	μA	V _R = 5 V	
	Capacity between terminals	CT		15		pF	V = 0, f = 1 MHz	
	Trigger LED forward current	I _{FT}		1.0	4.0	mA	I _O = 350 mA	
Output	Maximum resistance with output ON	R _{ON}		1.0	1.2	Ω	I _F = 5 mA, I _O = 350 mA	
	Current leakage when the relay is open	I _{leak}		0.2	1.0	nA	$V_{OFF} = 30$ V, Ta = 50°C	
	Capacity between terminals	COFF		30	40	pF	V = 0, f = 100 MHz	
Capacit	ty between I/O terminals	C _{I-O}		0.8		pF	f = 1 MHz, Vs = 0 V	
Insulation resistance		R _{I-O}	1,000			MΩ	$\begin{array}{l} V_{\text{I-O}} = 500 \text{ VDC}, \\ R_{\text{oH}} \leq 60\% \end{array}$	
Turn-ON time		t _{on}		0.3	0.5	ms	$I_{\rm F} = 5 {\rm mA}, R_{\rm L} = 200 \Omega,$	
Turn-OFF time		t _{OFF}		0.3	0.5	ms	$V_{DD} = 20 V$ (See note 2.)	

2. Turn-ON and Turn-OFF Times



Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Load voltage (AC peak/DC)	V _{DD}			64	V
Operating LED forward current	I _F	5		30	mA
Continuous load current (AC peak/DC)	I _o			350	mA
Operating temperature	T _a	25		60	°C

 The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

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1.4

60

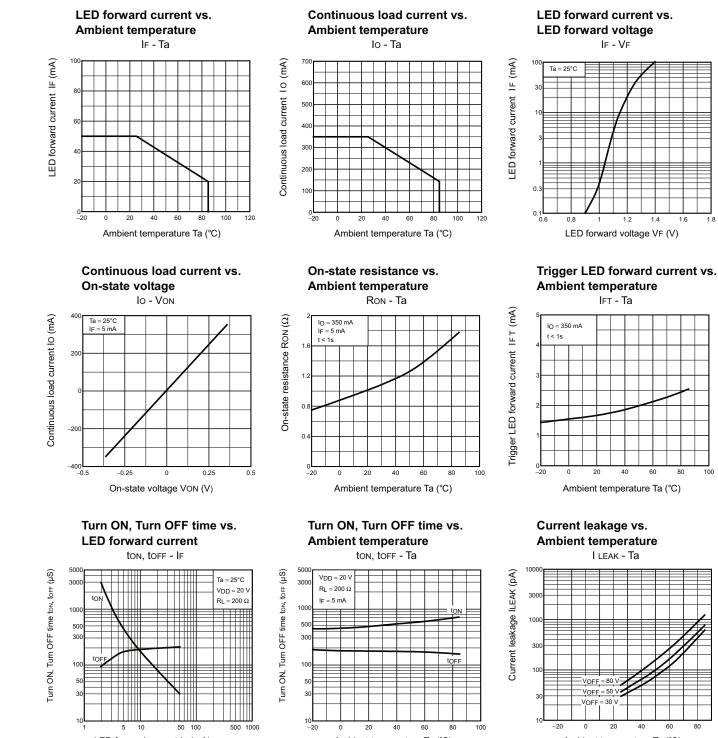
80

100

80

Ambient temperature Ta (°C)

1.6



60

Ambient temperature Ta (°C)

Engineering Data

5 10

LED forward current IF (mA)

100

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ALL DIMENSIONS SHOWN ARE IN MILLIMETERS. To convert millimeters into inches, multiply by 0.03937. To convert grams into ounces, multiply by 0.03527.



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